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APPLICANTS

Hideto Sugawara, Kanagawa-ken, JAPAN;
 Tsunenori Hiratsuka, Kanagawa-ken, JAPAN;

** CONTINUING DATA ***** None AICS

** FOREIGN APPLICATIONS ***** Yes AICS
 JAPAN P2003-079387 03/24/2003

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Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 8	TOTAL CLAIMS 20	INDEPENDENT CLAIMS 3
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature: <i>Asish Kumar</i> Initials: <i>SK</i>				

ADDRESS
 000026021
 HOGAN & HARTSON L.L.P.
 500 S. GRAND AVENUE
 SUITE 1900
 LOS ANGELES, CA
 90071-2611

TITLE
 Group-III nitride semiconductor stack, method of manufacturing the same, and group-III nitride semiconductor device

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